

TECHNICAL DATA DATA SHEET 4508, REV. A

POWER SCHOTTKY RECTIFIER Low Reverse Leakage

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra Low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|---------------------------|--------------------|---|-------------|-------|
| Peak Inverse Voltage | V_{RWM} | - | 30 | V |
| Max. Average Forward | I _{F(AV)} | 50% duty cycle, rectangular | 30 | Α |
| Current | | wave form | | |
| Max. Peak One Cycle Non- | I _{FSM} | 8.3 ms, half Sine wave | 570 | Α |
| Repetitive Surge Current | | (per leg) | | |
| Non-Repetitive Avalanche | E _{AS} | $T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.3 \text{A},$ | 27 | mJ |
| Energy | | L = 40mH (per leg) | | |
| Repetitive Avalanche | I _{AR} | I _{AS} decay linearly to 0 in 1 μs | 1.3 | Α |
| Current | | f limited by T _J max V _A =1.5V _R | | |
| Thermal Resistance | R_{thJC} | Per Package | 0.90 | °C/W |
| Max. Junction Temperature | TJ | - | -65 to +150 | °C |
| Max. Storage Temperature | T _{stg} | - | -65 to +150 | °C |

Electrical Characteristics:

| Characteristics | Symbol | Condition | Max. | Units |
|---------------------------|-----------------|---|------|-------|
| Max. Forward Voltage Drop | V_{F1} | @ 15A, Pulse, T _J = 25 °C | 0.49 | V |
| | | (per leg) measured at the leads | | |
| | V_{F2} | @ 15A, Pulse, T _J = 125 °C | 0.39 | V |
| | | (per leg) measured at the leads | | |
| Max. Reverse Current | I_{R1} | $@V_R = 30V$, Pulse, | 4 | mA |
| | | T _J = 25 °C (per leg) | | |
| | I _{R2} | $@V_R = 30V$, Pulse, | 200 | mA |
| | | T _J = 125 °C (per leg) | | |
| Max. Junction Capacitance | C _T | $@V_R = 5 \text{ V}, T_C = 25 ^{\circ}\text{C}$ | 2200 | pF |
| | | f _{SIG} = 1 MHz, | | |
| | | $V_{SIG} = 50 \text{mV (p-p) (per leg)}$ | | |

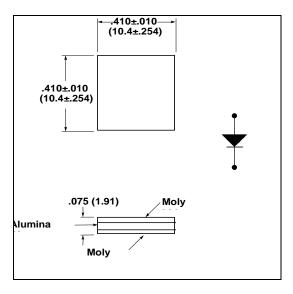
Due to the nature of the 30V Schottky devices, some degradation in t_{rr} performance at high temperatures should be expected, unlike conventional lower voltage Schottkys.

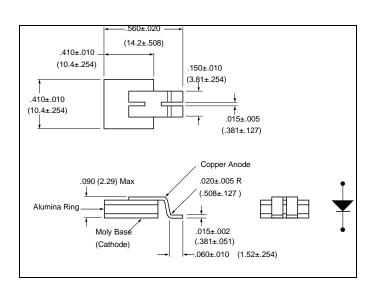
^{• 221} West Industry Court ☐ Deer Park, NY 11729-4681 ☐ (631) 586-7600 FAX (631) 242-9798 •

[•] World Wide Web Site - http://www.sensitron.com • E-Mail Address - sales@sensitron.com •

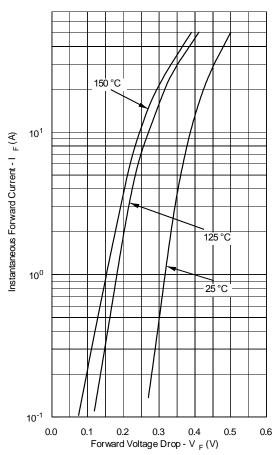
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Mechanical Dimensions: in inches / mm

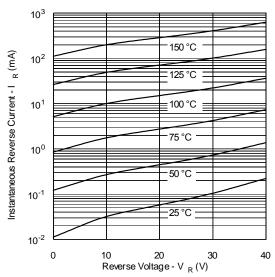




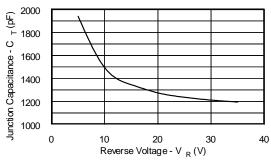
SHD-3 Typical Forward Characteristics



<u>SHD-3B</u> Typical Reverse Characteristics



Typical Junction Capacitance



Vf Curves shown are for die only.

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